

Нелинейный классический и линейный квантовый транспорт экситонов в двумерных кристаллах

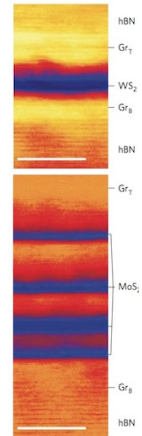
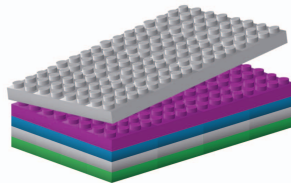
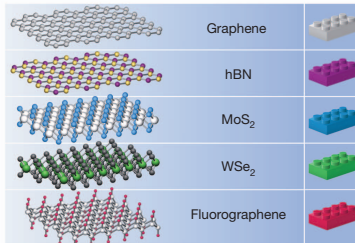
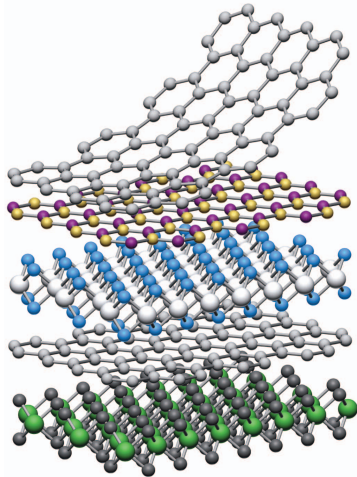
М.М. Глазов

ФТИ им. А.Ф. Иоффе, Санкт-Петербург

- 1 Краткое введение в физику двумерных кристаллов
- 2 Нелинейный транспорт экситонов
- 3 Слабая локализация экситонов
- 4 Заключение

Two-dimensional materials

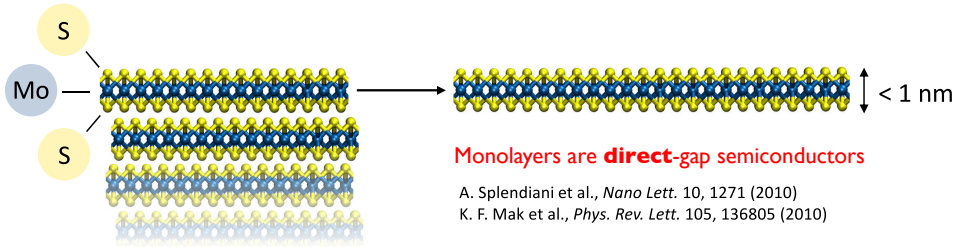
are the platform for van der Waals heterostructures



Withers et al. (2015)

Geim, Grigorieva (2013)

Transition metal dichalcogenides



A. Splendiani et al., *Nano Lett.* 10, 1271 (2010)

K. F. Mak et al., *Phys. Rev. Lett.* 105, 136805 (2010)

Bulk materials are **indirect-gap** semiconductors

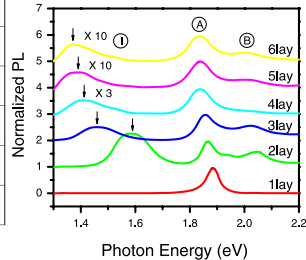
B. L. Evans & P. A. Young, *Proc. Phys. Soc.* 91, 475 (1967)

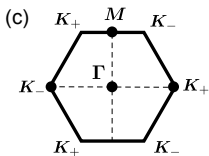
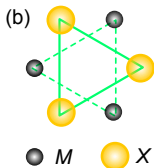
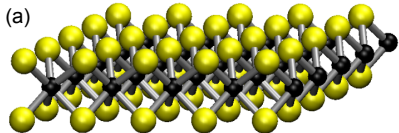
J. A. Wilson & A. D. Yoffe, *Adv. Phys.* 18, 193 (1969)

A. R. Beal et al. *J. Phys. C* 5, 3540 (1972)

A. Anedda et al. *Can. J. Phys.* (1979)

hydrogen 1 H 1.0079																	helium 2 He 4.0026														
lithium 3 Li 6.941	beryllium 4 Be 9.0122															neon 10 Ne 20.180															
sodium 11 Na 22.989	magnesium 12 Mg 24.305															argon 18 Ar 39.948															
potassium 19 K 39.098	calcium 20 Ca 40.078	scandium 21 Sc 44.956	titanium 22 Ti 47.867	vanadium 23 V 50.942	chromium 24 Cr 51.996	manganese 25 Mn 54.938	iron 26 Fe 55.845	cobalt 27 Co 58.933	nickel 28 Ni 58.693	copper 29 Cu 63.546	zinc 30 Zn 65.38	gallium 31 Ga 69.723	germanium 32 Ge 72.61	arsenic 33 As 74.922	selenium 34 Se 78.96	bromine 35 Br 79.904	krypton 36 Kr 83.80														
rubidium 37 Rb 85.468	strontium 38 Sr 87.62	yttrium 39 Y 88.906	zirconium 40 Zr 91.224	niobium 41 Nb 92.906	niobium 42 Mo 95.94	technetium 43 Tc [98]	ruthenium 44 Ru 101.07	rhodium 45 Rh 102.91	paladium 46 Pd 106.42	silver 47 Ag 107.87	cadmium 48 Cd 112.41	indium 49 In 114.82	tin 50 Sn 118.71	antimony 51 Sb 121.76	tellurium 52 Te 127.60	iodine 53 I 126.90	xenon 54 Xe 131.29														
cesium 55 Cs 132.91	barium 56 Ba 137.33	lanthanum 57 La 138.905	cerium 58 Ce 140.12	praseodymium 59 Pr 140.908	neodymium 60 Nd 144.24	promethium 61 Pm [145]	samarium 62 Sm 150.36	europium 63 Eu 151.96	gadolinium 64 Gd 157.25	terbium 65 Tb 158.925	dysprosium 66 Dy 162.50	holmium 67 Ho 164.930	erbium 68 Er 167.259	thulium 69 Tm 168.930	ytterbium 70 Yb 173.054	lutetium 71 Lu 174.967	hafnium 72 Hf 178.49	tantalum 73 Ta 180.948	tungsten 74 W 183.84	rhenium 75 Re 186.207	osmium 76 Os 190.23	iridium 77 Ir 192.22	platinum 78 Pt 195.08	gold 79 Au 196.967	mercury 80 Hg 200.59	thallium 81 Tl 204.38	lead 82 Pb 207.2	bismuth 83 Bi 208.98	polonium 84 Po [209]	astatine 85 At [210]	radon 86 Rn [222]
francium 87 Fr [223]	radium 88 Ra [226]	actinium 89-102 * * *	thorium 90 Th [232]	protactinium 91 Pa [231]	uranium 92 U [238]	neptunium 93 Np [237]	plutonium 94 Pu [244]	americium 95 Am [243]	curium 96 Cm [247]	berkelium 97 Bk [247]	californium 98 Cf [251]	einsteinium 99 Es [252]	fermium 100 Fm [257]	mendelevium 101 Md [258]	nobelium 102 No [259]	lawrencium 103 Lr [260]	rutherfordium 104 Rf [261]	dubnium 105 Db [262]	seaborgium 106 Sg [263]	bohrium 107 Bh [264]	hassium 108 Hs [265]	meitnerium 109 Mt [266]	darmstadtium 110 Ds [267]	roentgenium 111 Uu [268]	copernicium 112 Uub [269]	unbinilium 114 Uuq [270]					





MoS_2 , MoSe_2 , WS_2 , WSe_2 , ...

D_{3h} point symmetry: horizontal reflection plane (σ_h), three-fold rotation axes (C_3 , S_3), $3C_2$, $2\sigma_v$

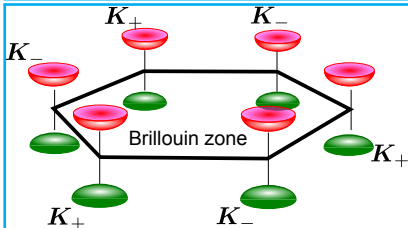
no space inversion: SO-splitting, second harmonic generation

Hexagonal Brillouin zone, direct band gaps are formed at the K_+ and K_- edges

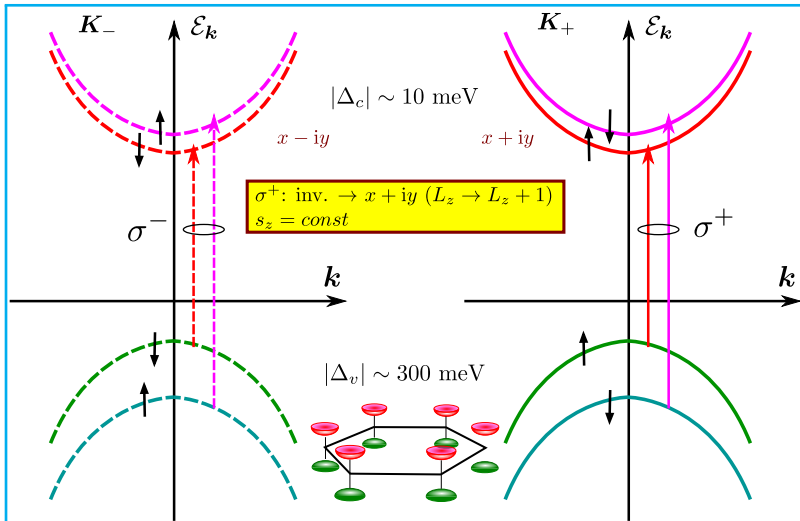
Valley symmetry is C_{3h} ; valleys are chiral

K_+ and K_- valleys are related by the time reversal symmetry

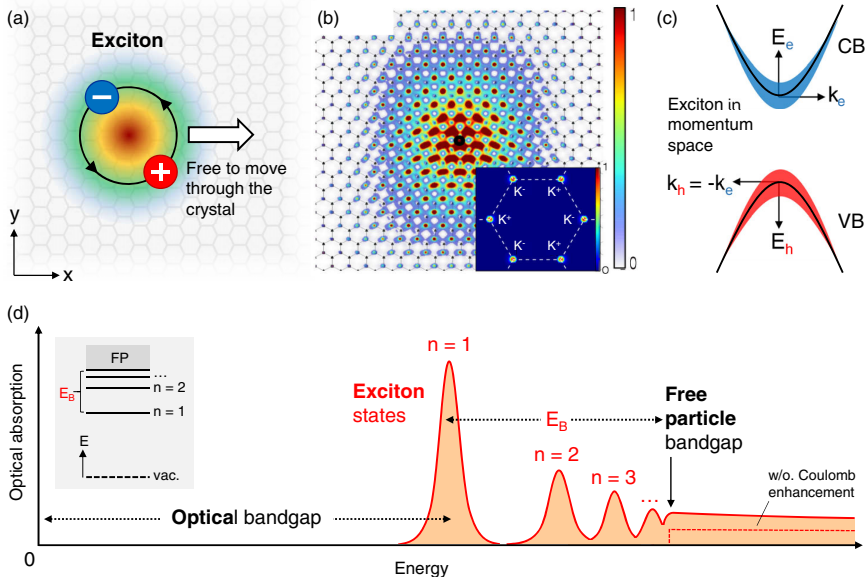
$$\mathcal{H}_{\text{eff}} = \hbar v(\boldsymbol{\sigma} \cdot \mathbf{k}) + \frac{E_g}{2}\sigma_z$$



Mo-based



Excitons in atom-thin semiconductors



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Эксперимент: [Университет Регенсбурга, Германия](#)



**Alexey
Chernikov**



**Marvin
Kulig**



**Jonas
Zipfel**

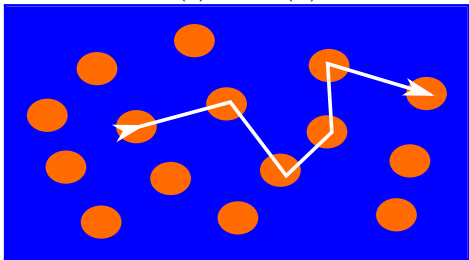


**Jonas
Ziegler**



**Rudolf
Richter**

Velocity: $\delta v(t) = \delta v(0)e^{-t/\tau_p}$

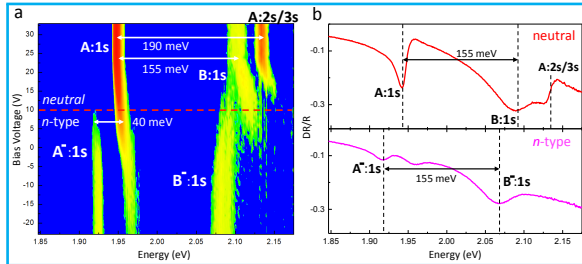


Velocity fluctuations:

$$\langle \delta v_x(t) \delta v_x(0) \rangle = \frac{v_T^2}{2} e^{-|t|/\tau_p} \quad (2D)$$

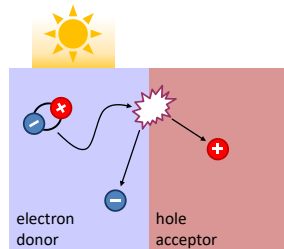
Diffusion coefficient

$$D = \int_0^\infty \langle \delta v_x(t) \delta v_x(0) \rangle dt = \frac{v_T^2 \tau_p}{2}$$

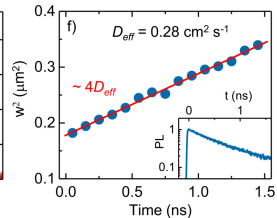
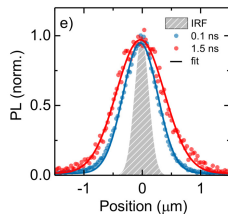
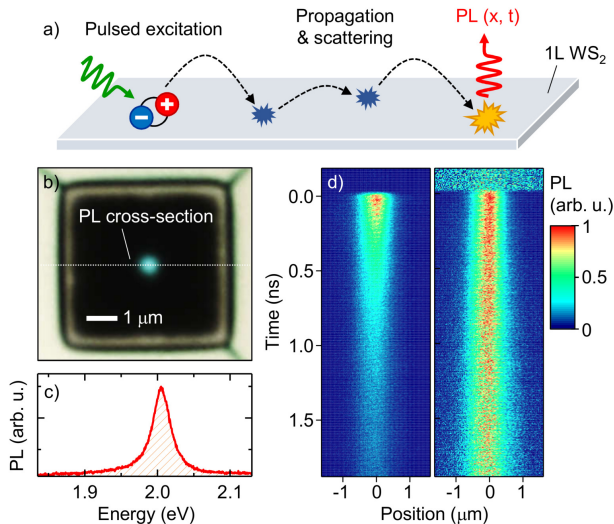


Phys. Rev. Materials 2, 011001(R) (2018)

Prospects: solar energy harvesting



Exciton diffusion: experimental puzzles

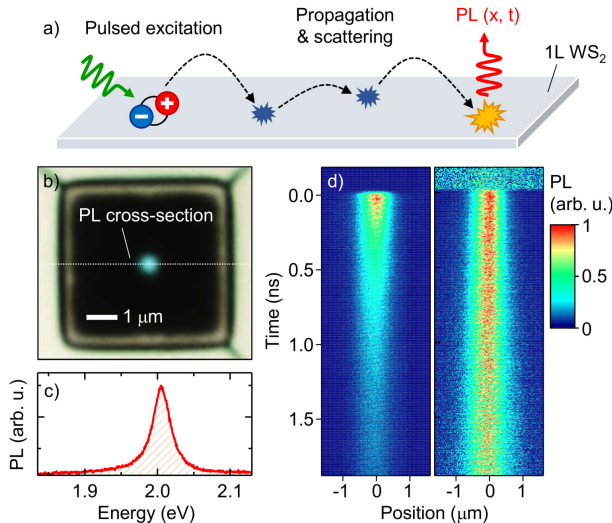


Optical access to transport phenomena

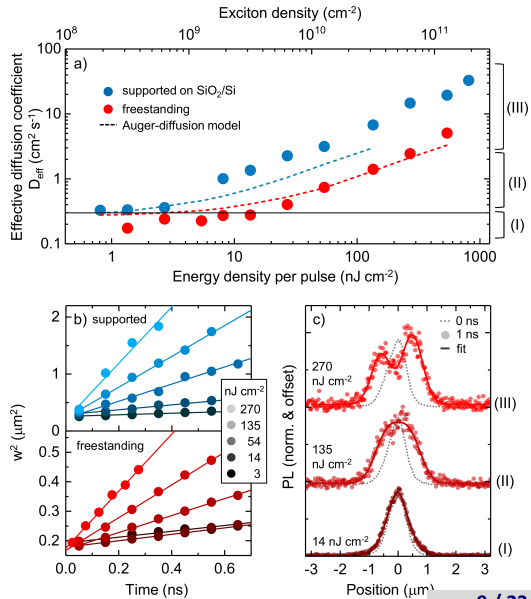
Exciton diffusion is observed

Most of excitons are dark
($K > \omega/c$; indirect; spin-valley forbidden)

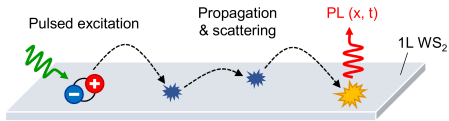
Exciton diffusion: experimental puzzles



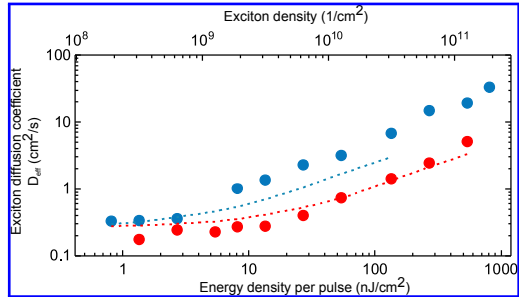
Phys. Rev. Lett. **120**, 207401 (2018)



Increase of effective diffusion coefficient: Auger effect



Experiment & Numerics:



Diffusion equation

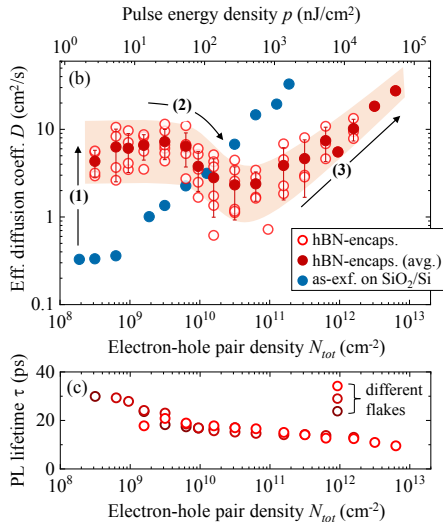
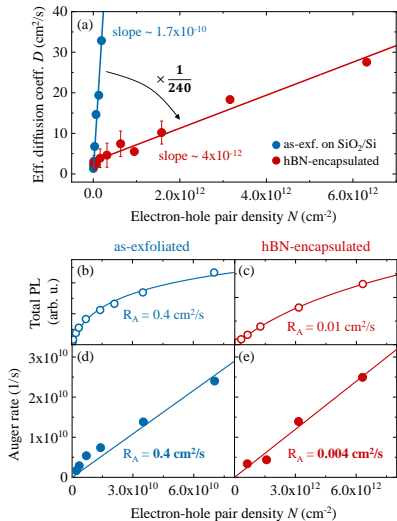
$$\frac{\partial n}{\partial t} = D\Delta n - \frac{n}{\tau} - R_A n^2 \quad R_A = (0.1 \dots 0.5) \frac{\text{cm}^2}{\text{s}}$$

Ansatz solution

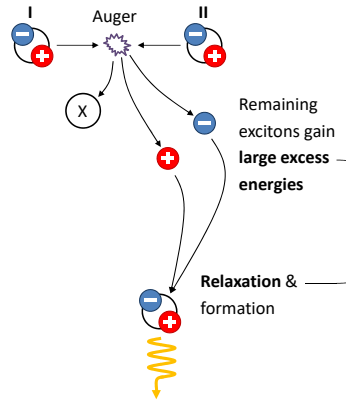
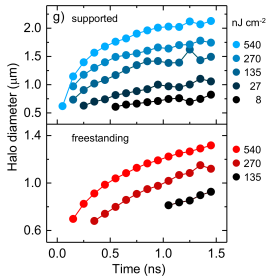
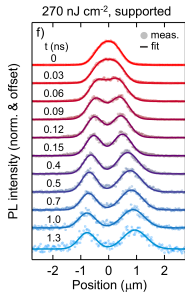
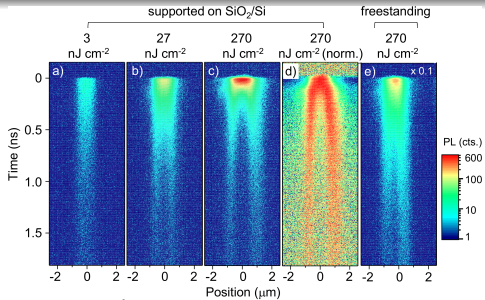
$$n(\rho, t) = \frac{N(t)}{\pi(r_0^2 + 4D_{eff}t)} \exp\left(-\frac{\rho^2}{r_0^2 + 4D_{eff}t}\right), \quad D_{eff} = D + \frac{R_A n_0 r_0^2}{16}$$

Suppression of Auger recombination effect \Rightarrow weaker increase of $D_{eff}(N)$

arXiv:1911.02909 (2019)



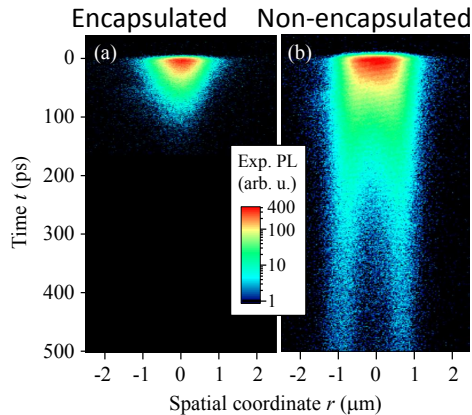
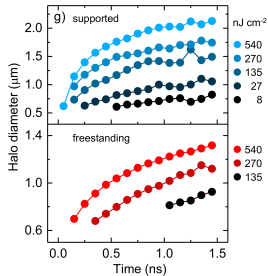
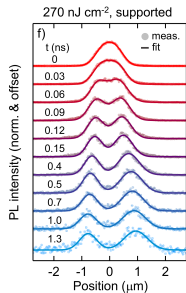
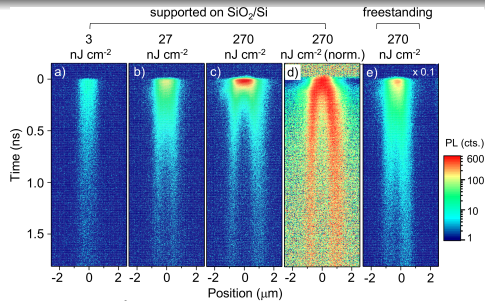
Excitonic halos: memory and heating effects



Excitons are overheated as a result of the Auger process
 non-equilibrium phonons are produced

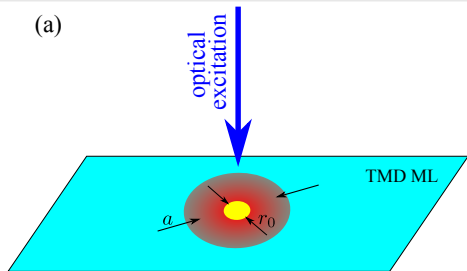
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Excitonic halos: memory and heating effects



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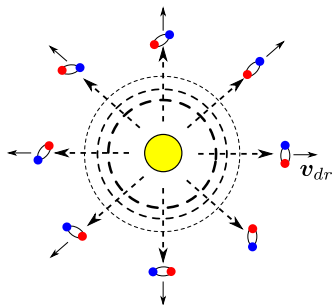
(a)



- Efficient Auger recombination
- Large energy release
- Excitation of non-equilibrium phonons

Phonons propagate out of the hot spot and drag excitons \Rightarrow halo-like pattern is formed

(b)



Drift-diffusion model

$$\frac{\partial n}{\partial t} + \nabla \cdot \mathbf{j} + \frac{n}{\tau} + R_A n^2 = 0,$$

$$\mathbf{j} = -D \nabla n + \frac{\tau_p}{m} \mathbf{F}(\rho) n$$

$$\mathbf{F} = \mathbf{F}_{\text{phonons}} + \mathbf{F}_{\text{Seebeck}}$$

Low temperatures, ballistic phonons

- Pump pulse creates hot spot
- ballistic phonons
- momentum flux



Phonons drag excitons away

Keldysh (1976); Zinov'ev, Ivanov, Kozub, Yaroshetskii (1983)
Bulatov, Tikhodeev (1992)

Force field produced by phonons (2D)

can be found from the kinetic equation

Exciton distribution function f_k :

$$\frac{\partial f_k}{\partial t} + v_k \frac{\partial f_k}{\partial r} + \frac{f_k - \bar{f}_k}{\tau_p} = -\frac{f_k}{\tau_d} + g_k$$

$$+ Q_{\text{exc-ph}}\{f_k\}$$

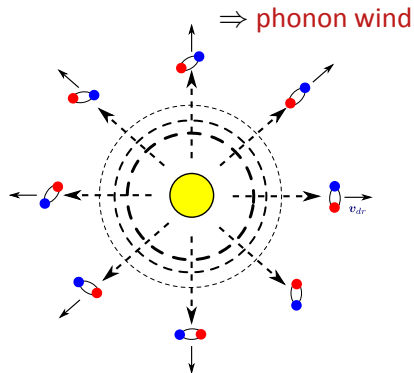
At $f_k \ll 1$, and high phonon occupancies $N_q \gg 1$

$$Q_{\text{exc-ph}}\{f_k\} = \frac{2\pi}{\hbar} \sum_q |M_q|^2 (f_{k+q} - f_k) \times$$

$$[N_q \delta(E_{k+q} - E_k - \hbar\Omega_q) + N_{-q} \delta(E_{k+q} - E_k + \hbar\Omega_q)]$$

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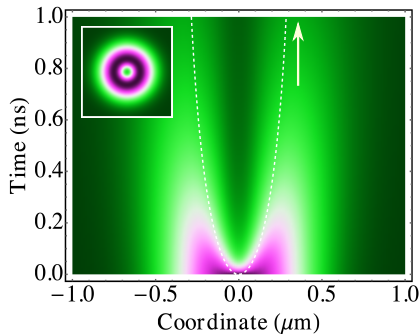
Force field produced by phonons (2D)

$$F_{\text{wind}}(\rho) = \frac{U \rho}{\rho \rho}$$

Hot spot acts as a repulsive center

effective "Coulomb" repulsion

Cloud expansion $\rho(t) \approx \sqrt{Ut}$

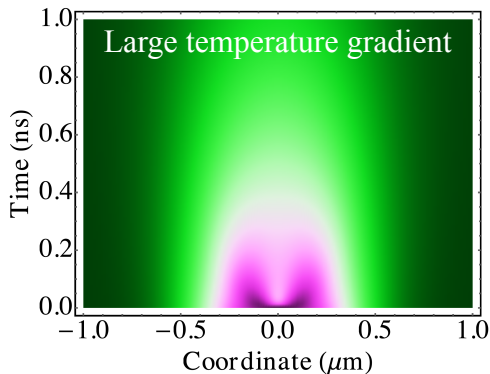
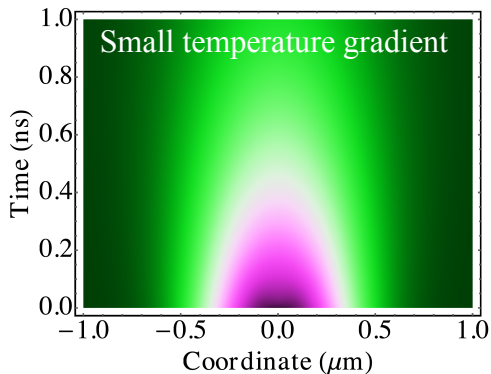


High temperatures, diffusive phonons

Temperature gradients of lattice and of excitons are formed

$$F_{\text{drag}} = -\frac{\tau_p}{\tau_x} k_B \nabla T_{\text{latt}}, \quad F_{\text{Seebeck}} = -k_B \nabla T_{\text{exc}}$$

Phonon drag scenario:



Phonon wind

Phonons propagate ballistically

$$F_{\text{wind}}(\rho) = \frac{U \rho}{\rho \rho}$$



These bluestripe snappers are schooling. They are all swimming in the same direction in a coordinated way.

Phonon drag

Phonons propagate diffusively

$$F_{\text{drag}}(\rho) = \nabla_{\rho} \frac{\Theta}{4\pi\kappa t} \exp\left(-\frac{\rho^2}{4\kappa t}\right)$$



These surgeonfish are shoaling. They are swimming somewhat independently, but in such a way that they stay connected.

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- Какие механизмы определяют коэффициент диффузии экситонов?
- Всегда ли применимо квазиклассическое описание?

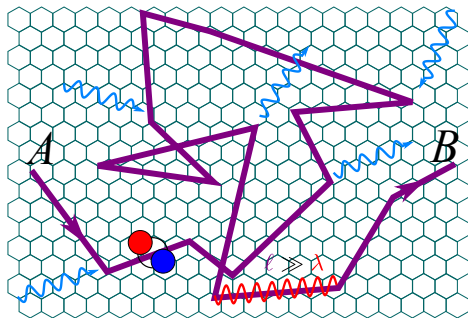
Non-degenerate excitons

$$\ell \gg \lambda \Rightarrow \frac{k_B T \tau}{\hbar} \gg 1$$

Diffusion coefficient

$$D = \left\langle \frac{v^2 \tau}{2} \right\rangle = \frac{k_B T \tau}{M} \gg \frac{\hbar}{M} \sim 1 \text{ cm}^2/\text{s},$$

otherwise **quantum effects** play role



LA-phonon scattering in MX_2 MLs

$$\tau = \frac{M s^2}{k_B T} \tau_0, \quad \tau_0^{-1} = \frac{M^2 (\Xi_c - \Xi_v)^2}{\rho \hbar^3} \Rightarrow D = s^2 \tau_0 \sim 1 \text{ cm}^2/\text{s}$$

In this mechanism D is temperature independent

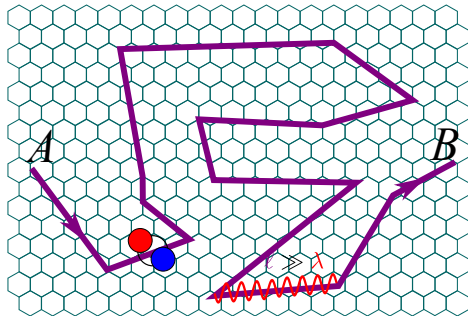
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Our goal

is to study the lowest order corrections in the parameter $\hbar / (k_B T \tau) \ll 1$.

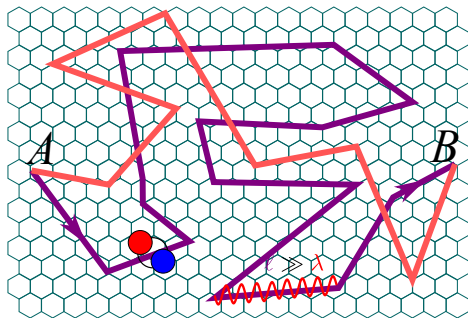
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$$P(A \rightarrow B) = \left| \sum_i \mathcal{A}_i \right|^2, \quad \mathcal{A}_i = |\mathcal{A}_i| \exp(i\phi_i)$$

$$\phi_i = \int_i \mathbf{k} \cdot d\mathbf{l}, \quad |\phi_i - \phi_j| \gtrsim k\ell \sim \frac{\ell}{\lambda} \gg 1 \Rightarrow P(A \rightarrow B) = \sum_i P_i \quad (?)$$

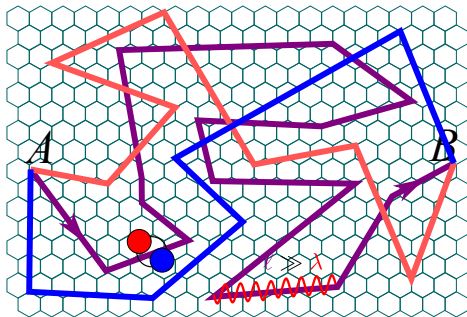
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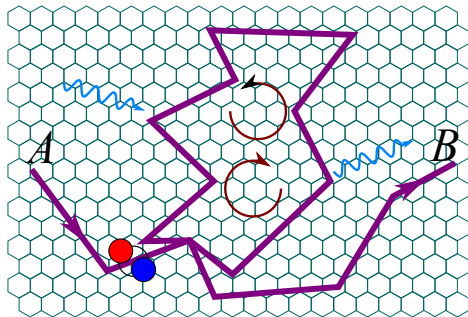
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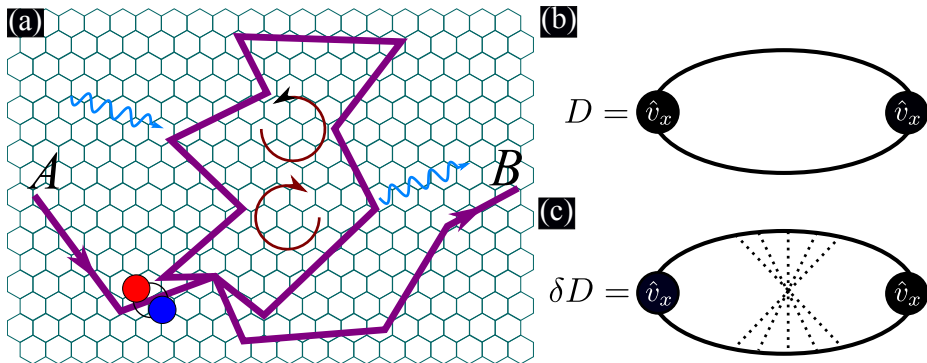


Self-intersecting trajectory:

$$\phi_{\circ} = \phi_{\circ}$$

Constructive interference \Rightarrow **localization**

$k_B T \gg M s^2 \sim 1 \text{ K}$ Quasi-elastic LA-phonon scattering



$$\frac{\delta D}{D} \sim - \int_{\tau}^{\tau_{\phi}} \frac{v_T \lambda dt}{Dt} \sim - \frac{\hbar}{k_B T \tau} \ln \left(\frac{\tau_{\phi}}{\tau} \right)$$

Exciton weak localization: Ivchenko, Pikus, Razbirin, Starukhin (1977), Arseev, Dzyubenko (1998)

Quasielasticity:

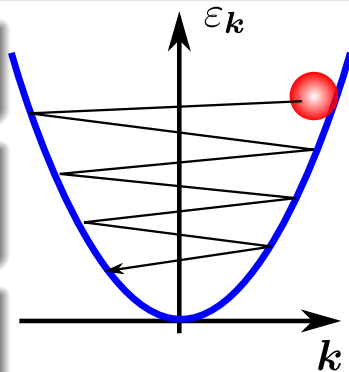
$$\Delta\epsilon \sim \sqrt{k_B T M s^2} \ll k_B T \quad \Rightarrow \quad \delta\epsilon^2(t) \sim (\Delta\epsilon)^2 \frac{t}{\tau}$$

Momentum relaxation time

$$\tau = \frac{M s^2}{k_B T} \tau_0, \quad \tau_0^{-1} = \frac{M^2 (\Xi_c - \Xi_v)^2}{\rho \hbar^3}$$

Energy relaxation time

$$\delta\epsilon(\tau_\epsilon) \sim k_B T \quad \Rightarrow \quad \tau_\epsilon = \frac{\tau_0}{2} \gg \tau$$

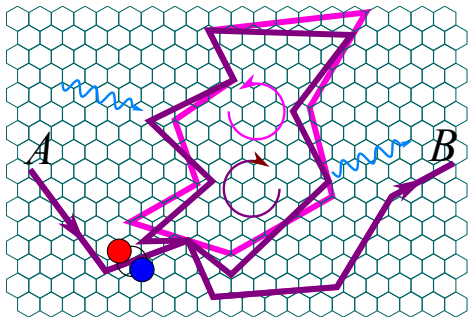


Phase relaxation time

$$\delta\epsilon(\tau_\phi) \sim \frac{\hbar}{\tau_\phi} \quad \Rightarrow \quad \tau_\phi \sim \left[\frac{\hbar^2 \tau_0}{(k_B T)^2} \right]^{1/3} \quad \Rightarrow \quad \frac{\tau_\phi}{\tau} \propto T^{1/3}$$

Quantum effects become more pronounced with the temperature increase

Dephasing due to phonon propagation



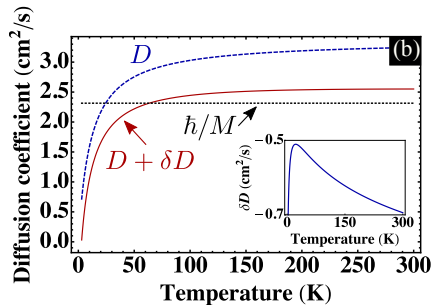
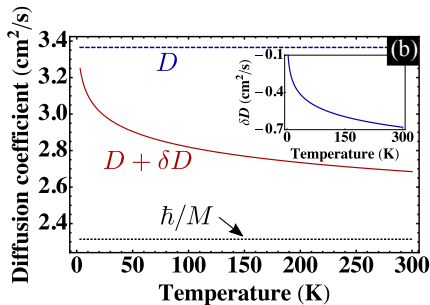
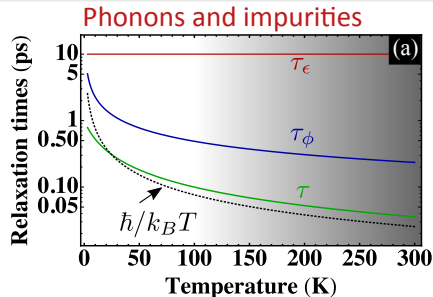
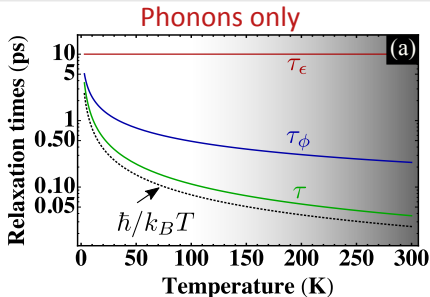
$$\begin{aligned} C_\phi &= \prod_i \exp \left\{ i \frac{\Delta p_i}{\hbar} [\mathbf{r}(t_i) - \mathbf{r}(-t_i)] \right\} \\ &\sim \exp \left\{ -\frac{M\epsilon^2}{\hbar^2\tau} \int_{-t}^t [\mathbf{r}(t') - \mathbf{r}(-t')]^2 dt' \right\} \\ &\sim \exp \left\{ -\frac{Ms^2\epsilon^2}{\hbar^2\tau} \int_{-t}^t (t')^2 dt' \right\} \sim \exp \left[-\frac{t^3}{\tau_\phi^3(\epsilon)} \right] \end{aligned}$$

ballistic phonons: $r(t) \sim st$

Phonons propagate with a constant velocity (s is the speed of sound), while the velocity of excitons increases with increasing the temperature.

Thus, dephasing is less efficient at elevated temperatures.

Weak localization: results

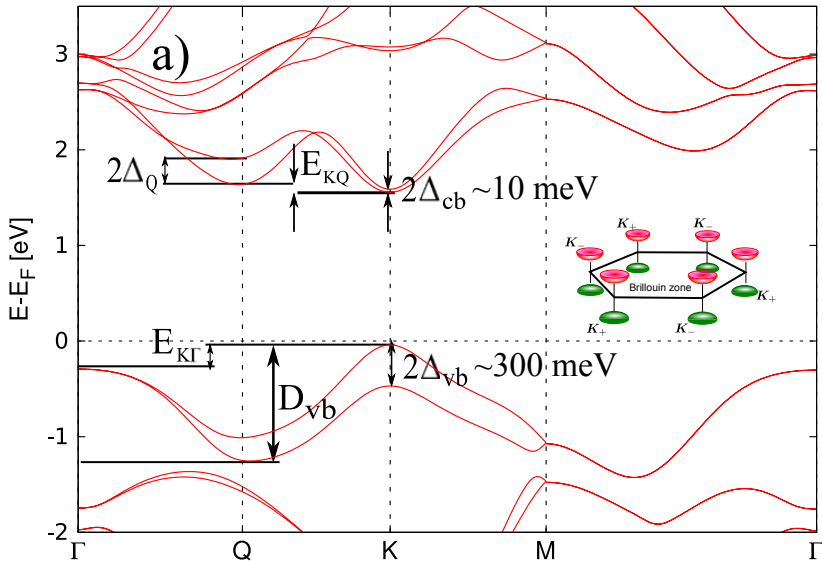


Take home message

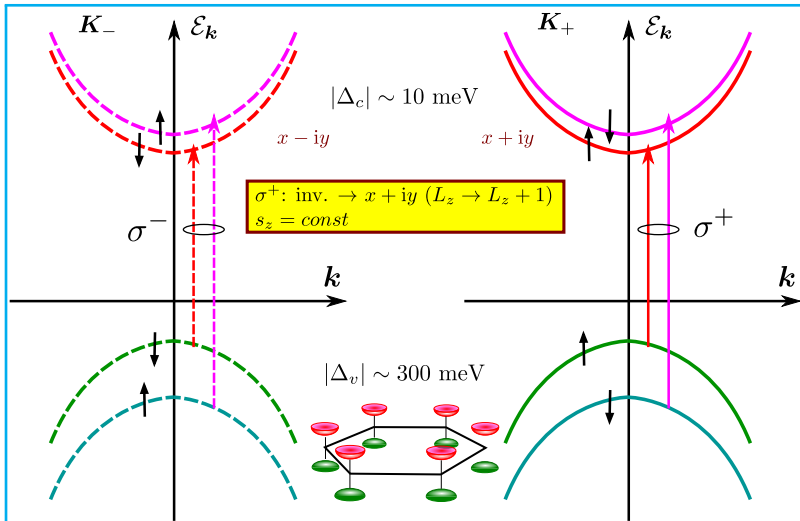
Excitons in 2D crystals are ideal objects to study linear and nonlinear transport effects.

Thank you for attention!

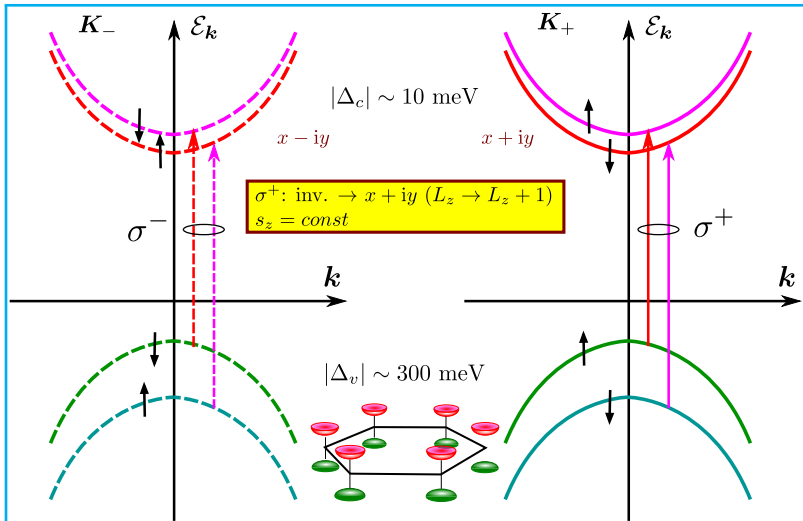
- | | |
|---|--|
| Kulig, ..., MMG, Chernikov,
MMG, | Exciton Diffusion and Halo Effects in Monolayer Semiconductors, Phys. Rev. Lett. 120 , 207401 (2018)
Phonon wind and drag of excitons in monolayer semiconductors, Phys. Rev. B 100 , 045426 (2019) |
| Zipfel, ..., MMG, Malic, Chernikov,
MMG, | Exciton diffusion in monolayer semiconductors with suppressed disorder, arXiv:1911.02909
Quantum interference effect on exciton transport in monolayer semiconductors, arXiv:1911.10528 |



Mo-based



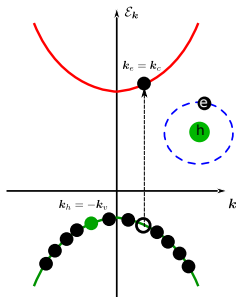
W-based



Optically created electron-hole pairs form excitons

$$\Psi_{\text{exc}} = \sum_{\mathbf{k}_e, \mathbf{k}_h} C_{\mathbf{k}_e, \mathbf{k}_h} |\mathbf{k}_e, s_e; \mathbf{k}_h, s_h\rangle = \sum_{\mathbf{k}_e, \mathbf{k}_h} C_{\mathbf{k}_e, \mathbf{k}_h} \mathcal{U}_\mu(\mathbf{k}_e, \mathbf{k}_h)$$

$|\mathbf{k}_e, s_e; \mathbf{k}_h, s_h\rangle$ is the wavefunction of the state where the $|\mathbf{k}_e, s_e\rangle$ conduction band state is occupied and the $|\mathbf{k}_h, s_h\rangle$ valence band state is empty



Exciton wavefunction

$$\Psi_{\mathbf{K}; \nu, \mu}(\rho_e, \rho_h) = \frac{\exp(i\mathbf{K}\mathbf{R})}{\sqrt{S}} \Phi_\nu(\rho) \mathcal{U}_\mu(\rho_e, \rho_h)$$

Envelope function (1s, 2p, ...)

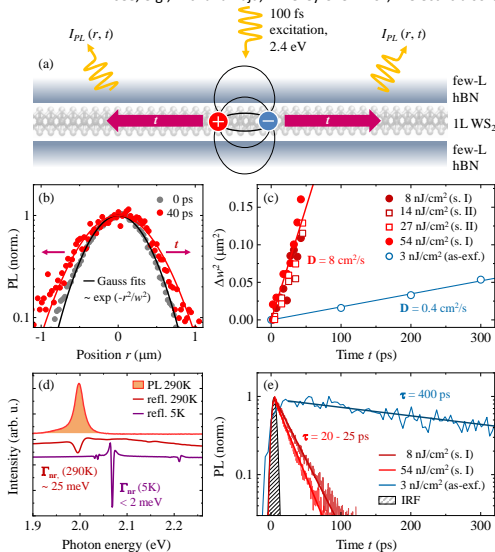
$$-\frac{\hbar^2}{2\mu} \Delta_\rho \Phi(\rho) + V(\rho) \Phi(\rho) = E \Phi(\rho)$$

Encapsulated vs. non-encapsulated structures



hBN encapsulation suppresses the dielectric disorder

see, e.g., Archana Raja, ...Alexey Chernikov, Dielectric disorder in two-dimensional materials, Nat. Nano. (2019)



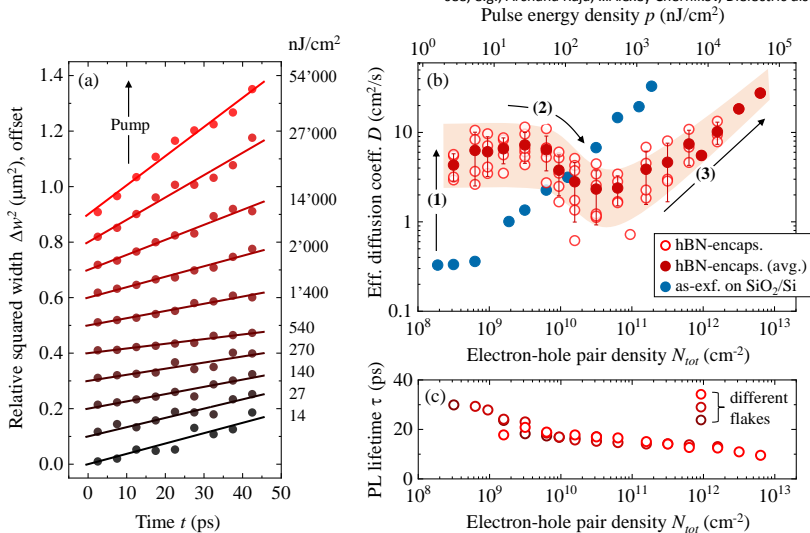
arXiv:1911.02909 (2019)

Encapsulated vs. non-encapsulated structures



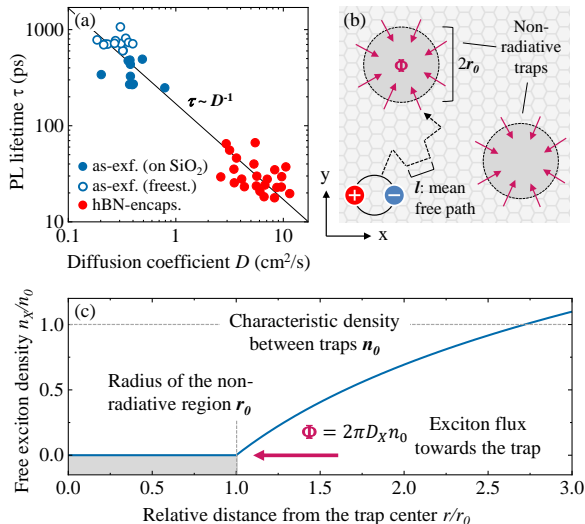
hBN encapsulation suppresses the dielectric disorder

see, e.g., Archana Raja, ...Alexey Chernikov, Dielectric disorder in two-dimensional materials, Nat. Nano. (2019)



arXiv:1911.02909 (2019)

Correlation of the diffusion coefficient and the lifetime



Exciton density near traps

$$D\Delta n_X = 0$$

Flux to the trap

$$|\Phi| = 2\pi r_0 D_X \left. \frac{dn}{dr} \right|_{r=r_0}$$

Lifetime

$$\frac{1}{\tau_r} \equiv \frac{N_{tr}\Phi}{n_0} = 2\pi D_X N_{tr}$$

Binding energy

$$E_b \approx 200 \text{ meV}$$

Ionization equilibrium

between excitons and plasma

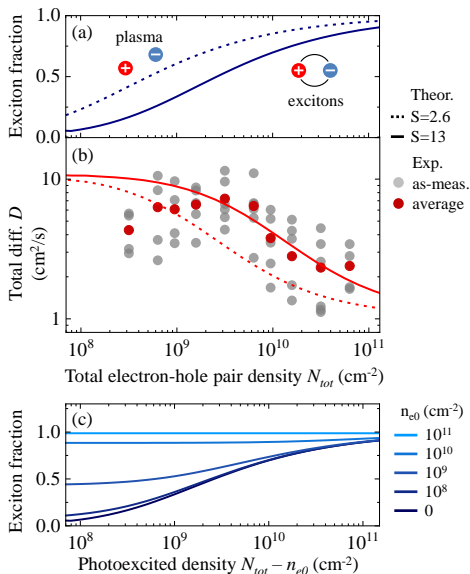
$$\frac{\bar{n}_X}{N_{tot}} = 1 + \frac{S}{2N_{tot}} - \sqrt{\left(\frac{S}{2N_{tot}}\right)^2 + \frac{S}{N_{tot}}}$$

Diffusion coefficients

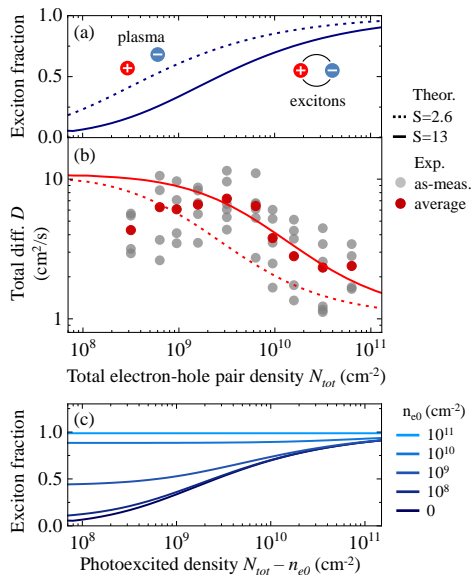
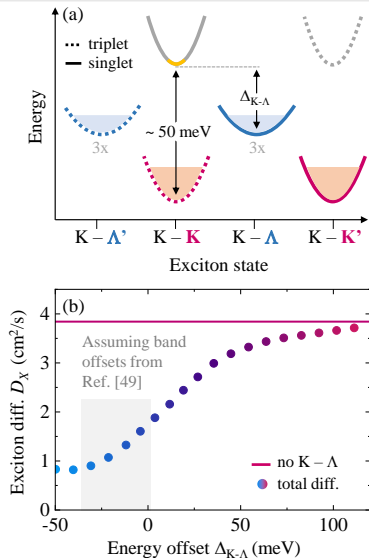
microscopic model (E. Malic et al.)

$$D_{eh} \approx 10 \text{ cm}^2/\text{s}; \quad D_X \approx 1 \text{ cm}^2/\text{s}$$

arXiv:1911.02909 (2019)

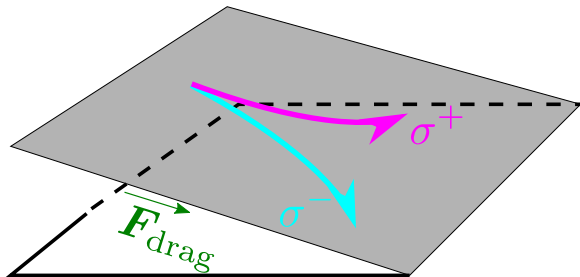


Electron-hole plasma vs. excitons



Valley Hall effect

Generation of the **valley** current transversal to the exciton flux $i_{\sigma} \propto [\sigma \times F_{\text{drag}}]$



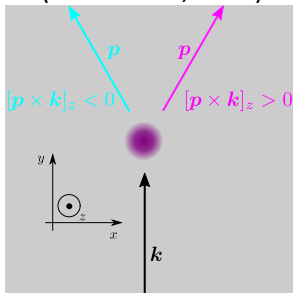
Drag force F_{drag} can be caused by

- Inhomogeneous deformation
- Exciton temperature gradient (Seebeck effect)
- **Phonon wind/drag** MMG (2019); Raúl Perea-Causín et al. (2019)

In conventional systems

E. Hall (1881): AHE in ferromagnets
Karplus, Luttinger (1954); Smith (1955): theory
M.I. Dyakonov, V.I. Perel (1971): SHE prediction
Y. Kato (2004); J. Wunderlich (2005): observation

Asymmetric scattering (Mott effect, skew)

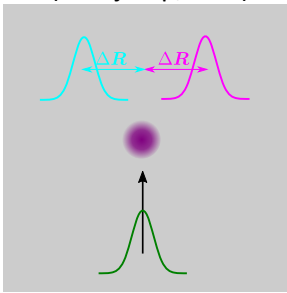


$$M_{pk} = M_q (1 + i\zeta [\mathbf{p} \times \mathbf{k}]_z \sigma_z)$$

$$i_{\sigma}^{skew} = \frac{\zeta}{\hbar} \frac{k_B T \tau}{\hbar} C_{as} [\mathbf{F}_{drag} \times \hat{\mathbf{z}}] N$$

$$|C_{as}| \ll 1$$

Shift of the wavepacket (side-jump, shift)

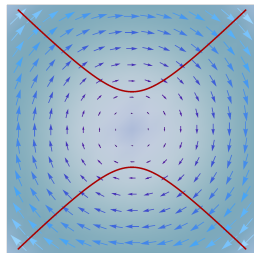


$$\Delta R_{pk} \propto \zeta [(\mathbf{p} - \mathbf{k}) \times \hat{\mathbf{z}}]$$

$$i_{\sigma}^{sj} \sim \frac{\zeta}{\hbar} [\mathbf{F} \times \hat{\mathbf{z}}] N$$

These contributions partially compensate each other

Anomalous velocity (intrinsic, Berry curvature)



$$v_a \propto \zeta [\mathbf{F} \times \hat{\mathbf{z}}]$$

$$i_{\sigma}^a \sim \frac{\zeta}{\hbar} [\mathbf{F} \times \hat{\mathbf{z}}] N$$

Exciton valley Hall effect: theoretical expectations

$$\frac{\partial n}{\partial t} = D\Delta n - f_{\text{drag}} \cdot \nabla n - \zeta f_{\text{drag}} \cdot \nabla \times \mathbf{S} - \frac{n}{\tau}, \quad \frac{\partial \mathbf{S}}{\partial t} = D\Delta \mathbf{S} - (f_{\text{drag}} \cdot \nabla) \mathbf{S} - \zeta f_{\text{drag}} \times \nabla n - \frac{\mathbf{S}}{T_s}$$

$$f_{\text{drag}} = \frac{\tau}{M} \mathbf{F}_{\text{drag}}, \quad \mathbf{S} = \sigma_z \hat{\mathbf{z}}$$

